NSN 5961-01-139-3388

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-139-3388

Inclosure Material:

Metal

Overall Height:

0.480 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

900.0 breakdown voltage, collector-to-emitter, base open

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

Yes - demil/mli

Fiig:

A110a0